1. Record Nr. UNINA9910229859503321 **Titolo** Australian animal protection law journal Beecroft, New South Wales, Australia:,: Lightoir Holdings Pty Ltd t/as Pubbl/distr/stampa Legal Bulletin Service, , [2008]-New South Wales, Australia:,: John Mancy t/as Legal Bulletin Service Balmain, NSW, Australia:,: John Mancy Descrizione fisica 1 online resource (volumes) Soggetti Animals - Law and legislation - Australia Animals - Law and legislation Periodicals. Australia Lingua di pubblicazione Inglese **Formato** Materiale a stampa

Periodico

Livello bibliografico

2. Record Nr. UNINA9910983353403321 Shankaranarayanan Krishna Autore **Titolo** Verification, Model Checking, and Abstract Interpretation: 26th International Conference, VMCAI 2025, Denver, CO, USA, January 20-21, 2025, Proceedings, Part II / / edited by Krishna Shankaranarayanan. Sriram Sankaranarayanan, Ashutosh Trivedi Cham: .: Springer Nature Switzerland: .: Imprint: Springer, . 2025 Pubbl/distr/stampa **ISBN** 9783031827037 3031827031 Edizione [1st ed. 2025.] Descrizione fisica 1 online resource (458 pages) Lecture Notes in Computer Science, , 1611-3349; ; 15530 Collana Altri autori (Persone) SankaranarayananSriram TrivediAshutosh 004.0151 Disciplina Soggetti Computer science Computer science - Mathematics Logic programming Computers, Special purpose Software engineering Theory of Computation Mathematics of Computing Logic in Al Special Purpose and Application-Based Systems Software Engineering Lingua di pubblicazione Inglese **Formato** Materiale a stampa Livello bibliografico Monografia Sommario/riassunto The two-volume set LNCS 15529 and 15530 constitutes the proceedings of the 26th International Conference on Verification, Model Checking, and Abstract Interpretation, VMCAI 2025, held in Denver, CO, USA, during January 20-21, 2025. The 20 full papers together with 2 accepted tool papers and 18 full length regular and case-study papers presented in the proceedings were carefully reviewed and

selected from 48 submissions. The program of VMCAI 2025 conference

in the core areas of VMCAI including abstract interpretation,

programming languages, hardware and software model checking, cyber-physical systems, formal synthesis, formal methods in artificial intelligence, concurrency and other areas.

Record Nr. UNINA9911019802903321

Autore Sangwal Keshra

Titolo Additives and crystallization processes : from fundamentals to

applications / / Keshra Sangwal

Pubbl/distr/stampa Chichester, England; ; Hoboken, NJ, : Wiley, c2007

ISBN 9786610974122

9781280974120 1280974125 9780470517833 0470517832 9780470517826 0470517824

Descrizione fisica 1 online resource (469 p.)

Disciplina 660/.284298

Soggetti Crystal growth

Nucleation Additives Crystallization

Lingua di pubblicazione Inglese

Formato Materiale a stampa

Livello bibliografico Monografia

Note generali Description based upon print version of record.

Nota di bibliografia Includes bibliographical references and indexes.

Nota di contenuto Additives and Crystallization Processes: Contents: Preface: 1

Complexes in Solutions; 1.1 Structure of Common Solvents; 1.2 Structure of Pure Aqueous Electrolyte Solutions; 1.2.1 Solvation of Electrolyte Ions in Solutions; 1.2.2 Concentrated and Saturated Electrolyte Solutions; 1.2.3 Formation of Aquo and Partially Aquo Complexes; 1.3 Structure of Aqueous Electrolyte Solutions Containing Additives; 1.4 Polyelectrolytes and Surfactants in Solutions; 1.5

Polydentate Ligands and Molecular Additives; 1.6 Crystal-Additive

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Sommario/riassunto

Crystal growth technology involves processes for the production of crystals essential for microelectronics, communication technologies, lasers and energy producing and energy saving technology. A deliberately added impurity is called an additive and in different industries these affect the process of crystal growth. Thus, understanding of interactions between additives and the crystallizing phases is important in different processes found in the lab, nature and in various industries. This book presents a generalized description of the mechanisms of action of additives during nucleation, grow